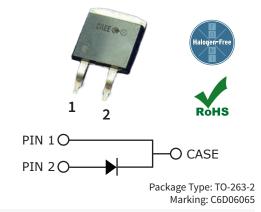


C6D06065G

6th Generation 650 V, 6 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.



Features

- Low Forward Voltage (V_r) Drop with Positive **Temperature Coefficient**
- Zero Reverse Recovery Current / Forward **Recovery Voltage**
- Temperature-Independent Switching Behavior
- Low Leakage Current (I_P)

Applications

- Industrial Power Supplies
- Switch Mode Power Supplies
- Server / Telecom Power Supplies
- **Power Factor Correction**
- Solar Inverter
- Uninterruptible Power Supply

Maximum Ratings ($T_c = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Value	Unit	Test Conditions	Note
Repetitive Peak Reverse Voltage	V _{RRM}	650	- V		
DC Blocking Voltage	V _{DC}	650	- V		
		23		T _J = 25 °C	
Continuous Forward Current	I _F	12	-	T _J = 125 °C	Fig. 3
		6	_	T _J = 155 °C	
Repetitive Peak Forward Surge		25	P	T _c = 25 °C, t _p = 10 ms, Half Sine Wave	
Current	FRM	14		$T_c = 110 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	
		45	-	$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	F i= 0
Non-Repetitive Peak Forward	FSM	33	-	$T_c = 110 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$	Fig. 8
Surge Current		620	_	$T_{c} = 25 \text{ °C}, t_{p} = 10 \mu\text{s}, \text{Pulse}$	
	F, Max	570	-	T _c = 110 °C, t _p = 10 μs, Pulse	
Power Dissipation	P _{tot} -	73	- W	T _J = 25 °C	
		31		T ₁ = 110 °C	Fig. 4



Electrical Characteristics

Parameter	Symbol	Тур. Мах.		Units	Test Conditions	Note	
	N	1.27	1.40	M	I _F = 6 A, T _J = 25 °C		
Drain-Source Voltage	V _F	1.37	1.50	— V	I _F = 6 A, T _J = 175 °C	— Fig. 1	
Deverse Current		2	20		$V_{R} = 650 \text{ V}, \text{ T}_{J} = 25 \text{ °C}$		
Reverse Current	I _R	25	200	— μΑ	V _R = 650 V, T _J = 175 °C	— Fig. 2	
Total Capacitive Charge	Q _c	22		nC	$V_{R} = 400 \text{ V}, \text{ T}_{J} = 25 \text{ °C}$	Fig. 5	
	$\frac{393}{V_{R}} = 0 \text{ V}, \text{ T}_{J} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$						
Total Capacitance		44	pF		V_{R} = 200 V, T_{J} = 25 °C, f = 1 MHz	- Fig. 6	
		36			$V_{R} = 400 \text{ V}, \text{ T}_{J} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$	-	
Capacitance Stored Energy	E _c	3.5		μJ	V _R =400 V	Fig. 7	

Note:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

Parameter	Symbol	Тур.	Units	Note
Thermal Resistance, Junction to Case	$R_{_{\theta,JC}}$	2.05	°C / W	
Operating Junction & Storage Temperature	T_{J},T_{stg}	-55 to +175	°C	Fig. 9

Typical Performance

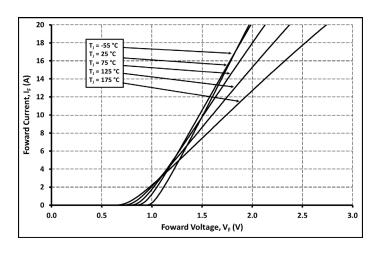


Figure 1. Forward Characteristics

Figure 2. Reverse Characteristics

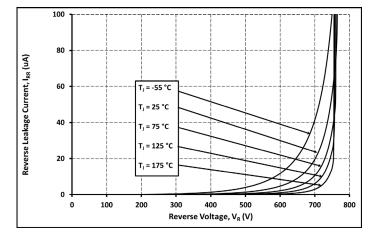
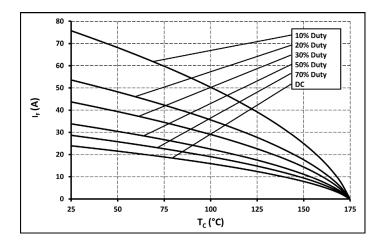


Figure 3. Current Derating





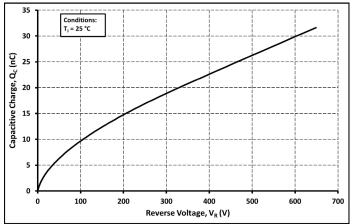


Figure 4. Power Derating

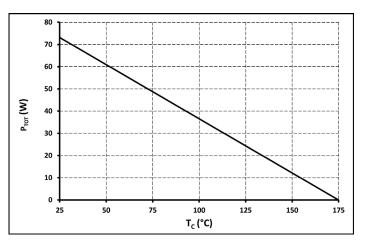
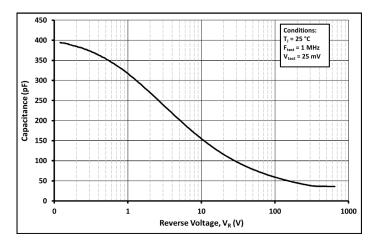


Figure 6. Capacitance vs. Reverse Voltage



Typical Performance

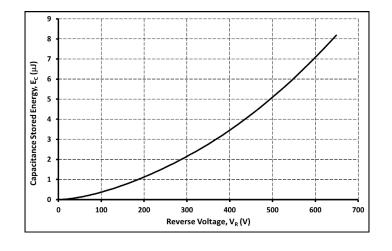
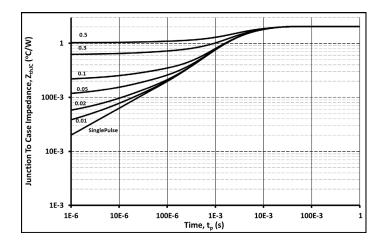


Figure 7. Capacitance Stored Energy

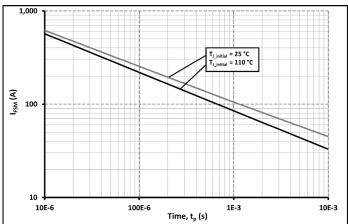
Figure 9. Transient Thermal Impedance



Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Class
Human Body Model	НВМ	Class 3B (≥ 8000 V)
Charge Device Model	CDM	Class C3 (≥ 1000 V)

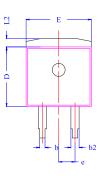


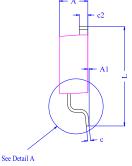


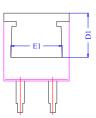
Current (Sine Wave)

Package Dimensions

Package: TO-263-2 All dimensions in mm.





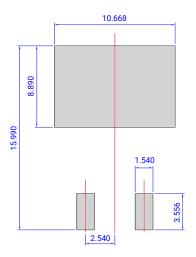




Rotated 90°

ax
57
25
94
.4
535
.4
.4
88
.28
25
.75
79
39
3°

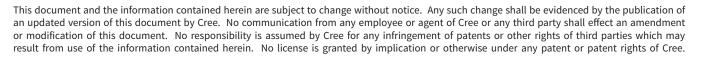
Recommended Solder Pad Layout



Learn more about recommended soldering profiles in this application note.

C6D06065G





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This product has not been designed or tested for use in, and is not intended for use in, applications in which failure of the product would reasonably be expected to cause death, personal injury, or property damage, including but not limited to equipment implanted into the human body, life-support machines, cardiac defibrillators, and similar emergency medical equipment, aircraft navigation, communication, and control systems, aircraft power and propulsion systems, air traffic control systems, and equipment used in the planning, construction, maintenance, or operation of nuclear facilities.

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For more information, please contact:

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